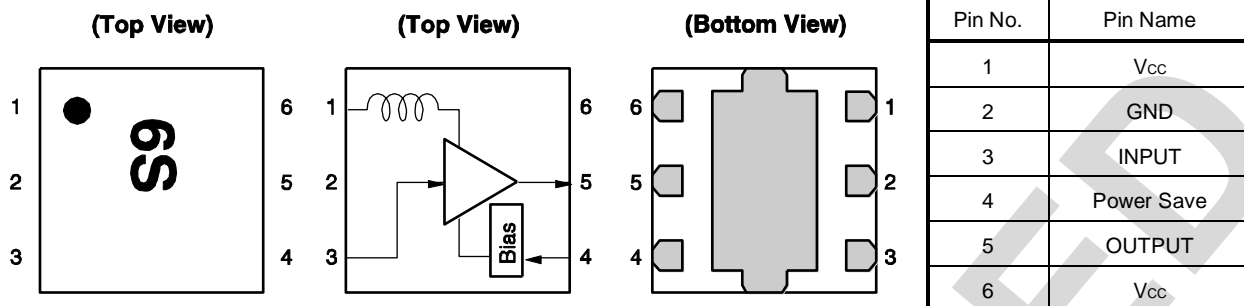


PIN CONNECTIONS AND INTERNAL BLOCK DIAGRAM



Remark Exposed pad : GND

ABSOLUTE MAXIMUM RATINGS

Parameter	Symbol	Test Conditions	Ratings	Unit
Supply Voltage	V _{CC}	T _A = +25°C	4.0	V
Power-Saving Voltage	V _{PS}	T _A = +25°C	4.0	V
Total Power Dissipation	P _{tot}		150	mW
Operating Ambient Temperature	T _A		−40 to +85	°C
Storage Temperature	T _{stg}		−55 to +150	°C
Input Power	P _{in}		+10	dBm

RECOMMENDED OPERATING RANGE

Parameter	Symbol	MIN.	TYP.	MAX.	Unit
Supply Voltage	V _{CC}	1.6	2.7	3.3	V
Operating Ambient Temperature	T _A	−40	+25	+85	°C
Power Save Turn-on Voltage	V _{PSon}	1.0	–	V _{CC}	V
Power Save Turn-off Voltage	V _{PSoff}	0	–	0.4	V

ELECTRICAL CHARACTERISTICS

(T_A = +25°C, V_{CC} = V_{PS} = 2.7 V, f_{in} = 1 575 MHz, unless otherwise specified)

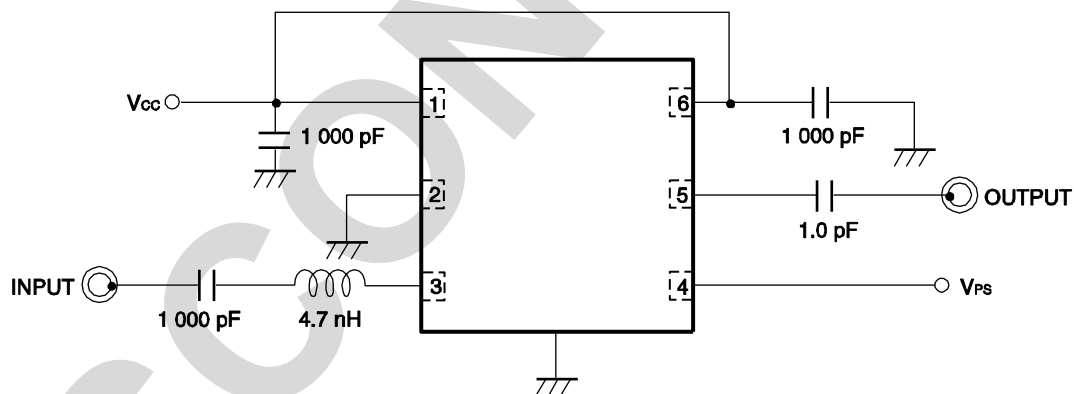
Parameter	Symbol	Test Conditions	MIN.	TYP.	MAX.	Unit
Circuit Current	I _{CC}	No Signal (V _{PS} = 2.7 V)	5.0	6.5	8.0	mA
		At Power-Saving Mode (V _{PS} = 0 V)	–	–	1	μA
Power Gain	G _P	P _{in} = −35 dBm	17	19.5	22	dB
Noise Figure	NF		–	0.8	1.1	dB
Input Return Loss	RL _{in}		7.5	11	–	dB
Output Return Loss	RL _{out}		11	14	–	dB

STANDARD CHARACTERISTICS FOR REFERENCE 1(T_A = +25°C, V_{CC} = V_{PS} = 2.7 V, f_{in} = 1 575 MHz, unless otherwise specified)

Parameter	Symbol	Test Conditions	Reference	Unit
Input 3rd Order Intercept Point	IIP ₃	f _{in1} = 1 575 MHz, f _{in2} = 1 574 MHz	−3	dBm
Isolation	ISL		39	dB
Gain 1 dB Compression Input Power	P _{in} (1 dB)		−18	dBm

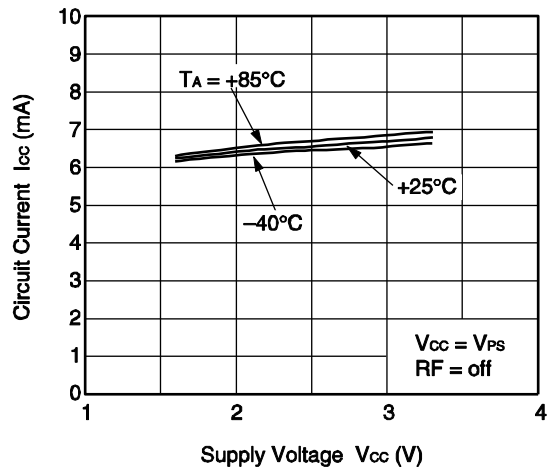
STANDARD CHARACTERISTICS FOR REFERENCE 2(T_A = +25°C, V_{CC} = V_{PS} = 1.8 V, f_{in} = 1 575 MHz, unless otherwise specified)

Parameter	Symbol	Test Conditions	Reference	Unit
Circuit Current	I _{CC}	No Signal (V _{PS} = 1.8 V)	6.2	mA
Power Gain	G _P	P _{in} = −35 dBm	19.1	dB
Noise Figure	NF		0.8	dB
Input 3rd Order Intercept Point	IIP ₃	f _{in1} = 1 575 MHz, f _{in2} = 1 574 MHz	−5	dBm
Input Return Loss	RL _{in}		11	dB
Output Return Loss	RL _{out}		14	dB
Isolation	ISL		39	dB
Gain 1 dB Compression Input Power	P _{in} (1 dB)		−19	dBm

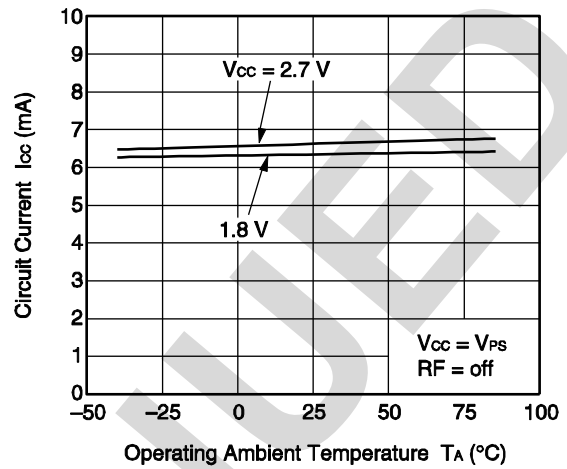
TEST CIRCUIT

TYPICAL CHARACTERISTICS ($T_A = +25^\circ\text{C}$, unless otherwise specified)

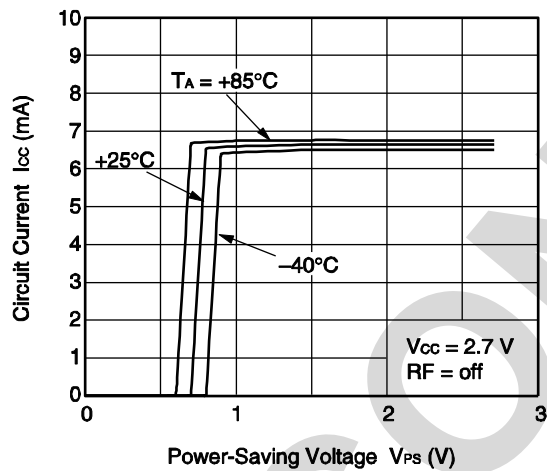
CIRCUIT CURRENT vs. SUPPLY VOLTAGE



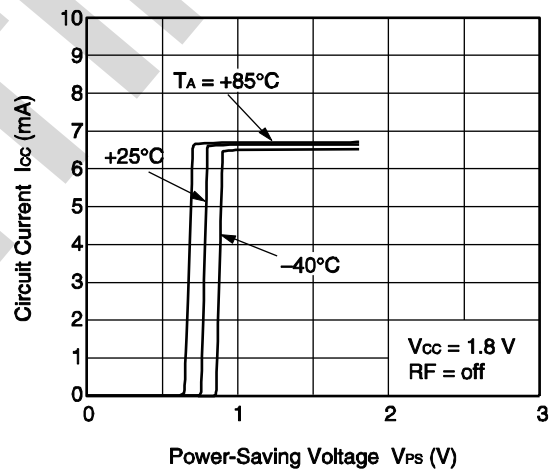
CIRCUIT CURRENT vs. OPERATING AMBIENT TEMPERATURE



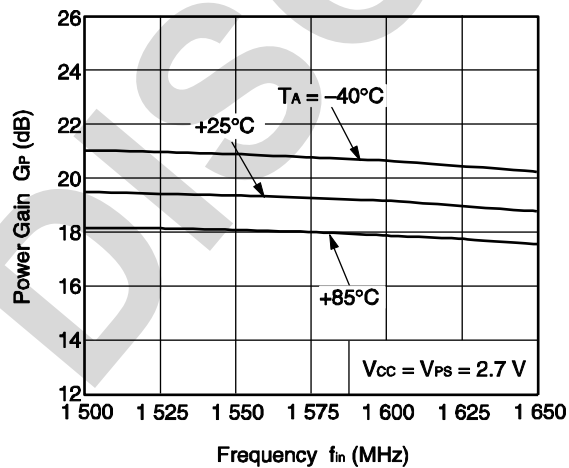
CIRCUIT CURRENT vs. POWER-SAVING VOLTAGE



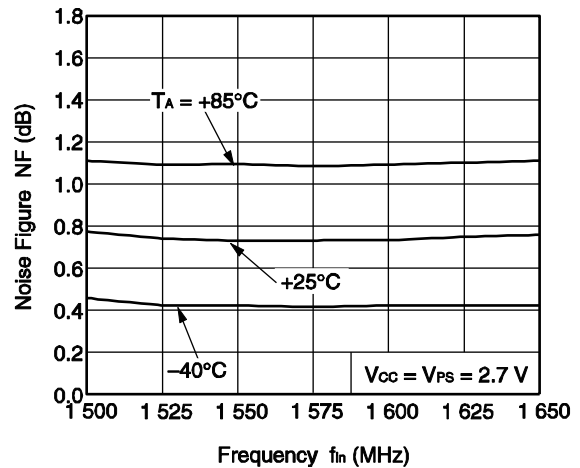
CIRCUIT CURRENT vs. POWER-SAVING VOLTAGE



POWER GAIN vs. FREQUENCY

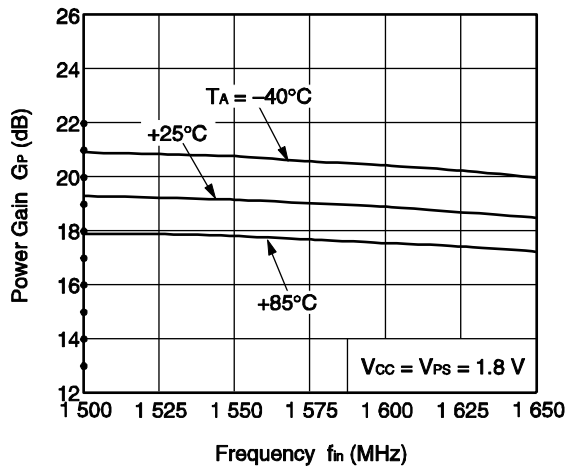


NOISE FIGURE vs. FREQUENCY

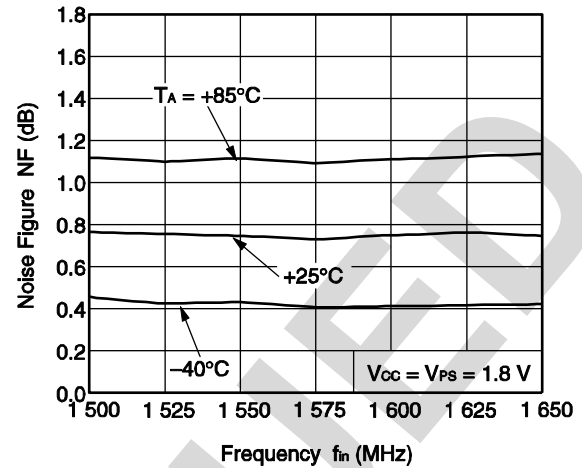


Remark The graphs indicate nominal characteristics.

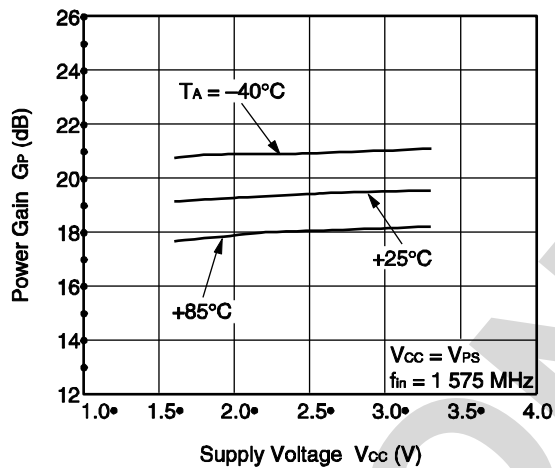
POWER GAIN vs. FREQUENCY



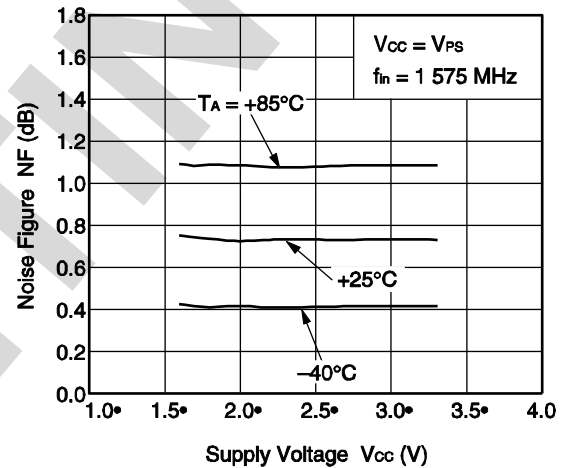
NOISE FIGURE vs. FREQUENCY



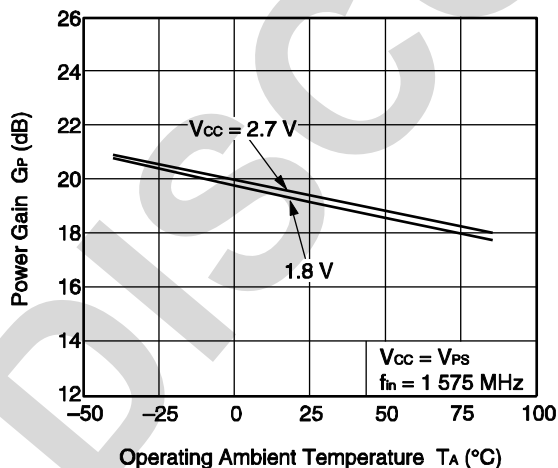
POWER GAIN vs. SUPPLY VOLTAGE



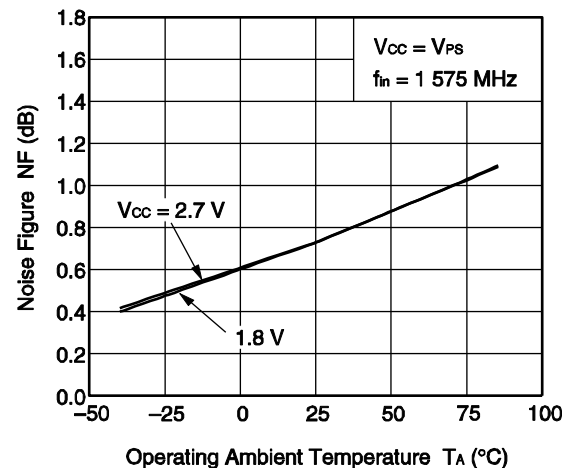
NOISE FIGURE vs. SUPPLY VOLTAGE



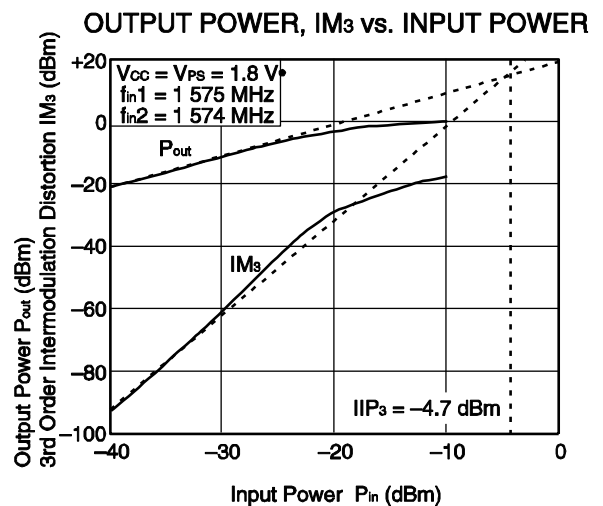
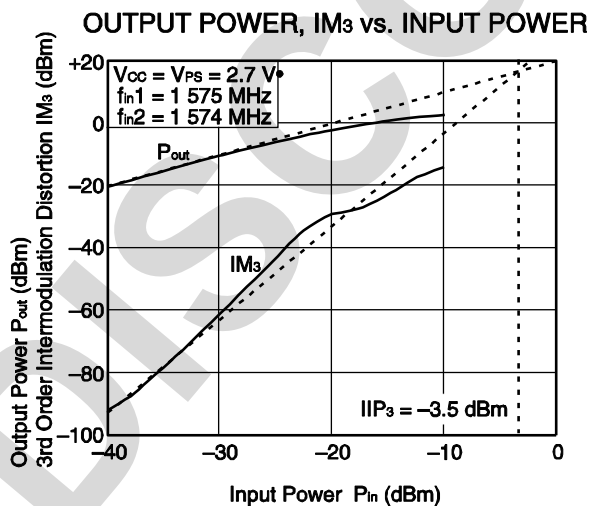
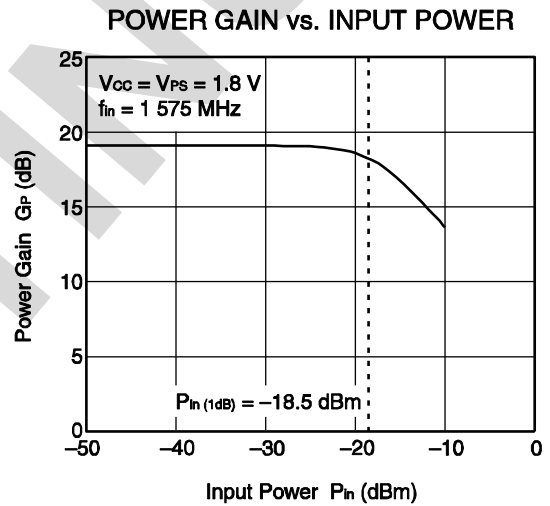
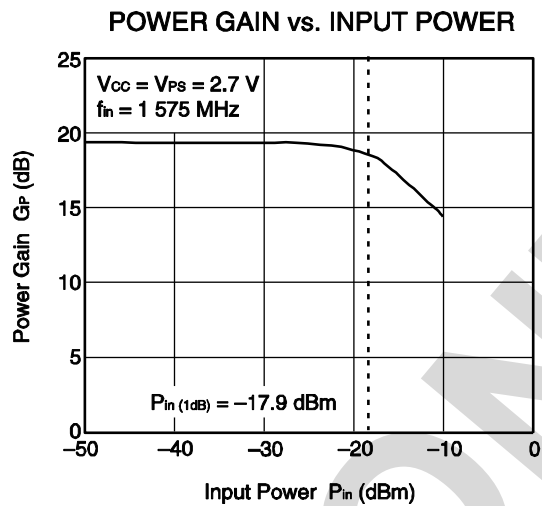
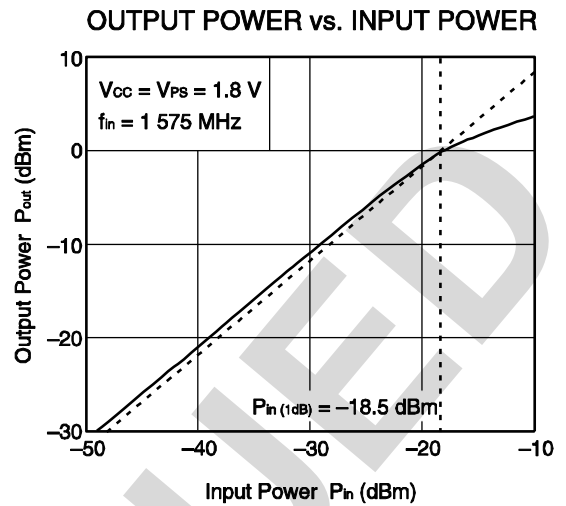
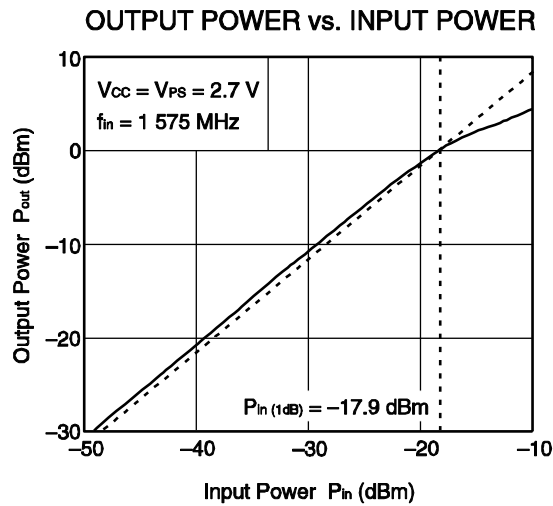
POWER GAIN vs. OPERATING AMBIENT TEMPERATURE



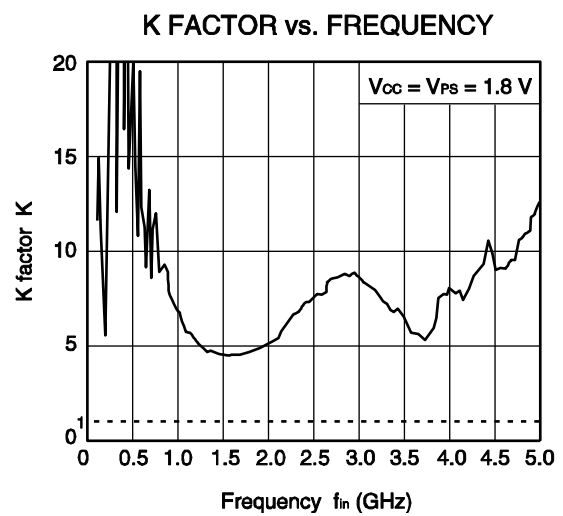
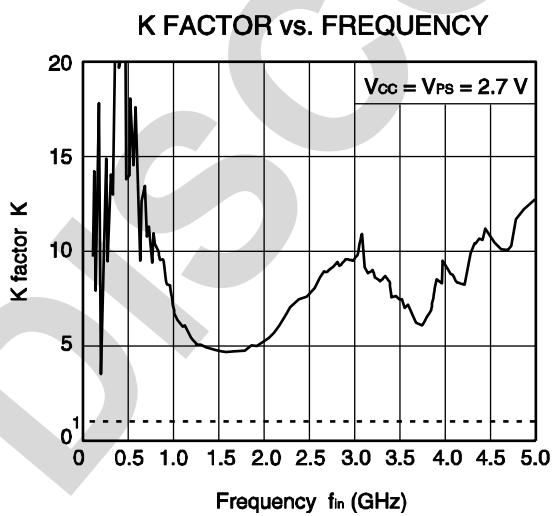
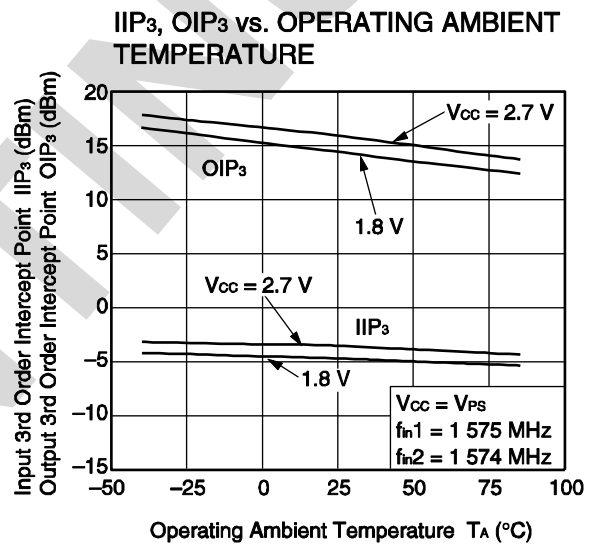
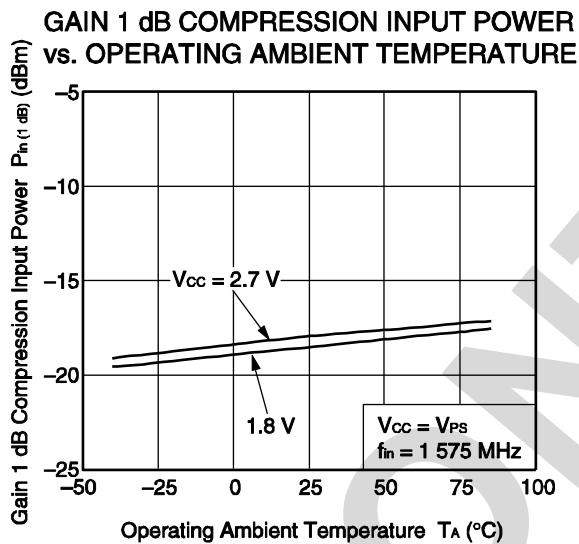
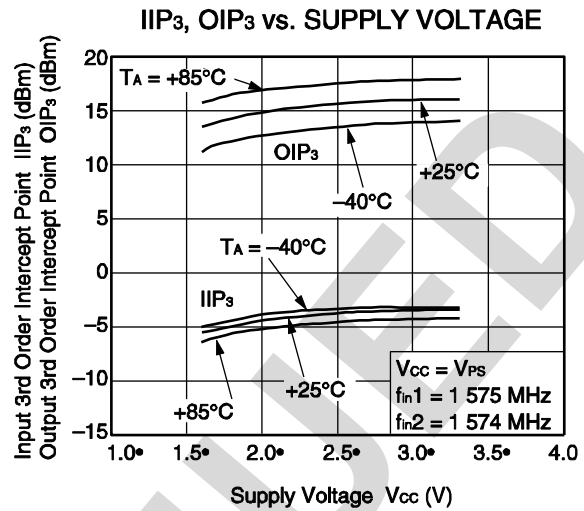
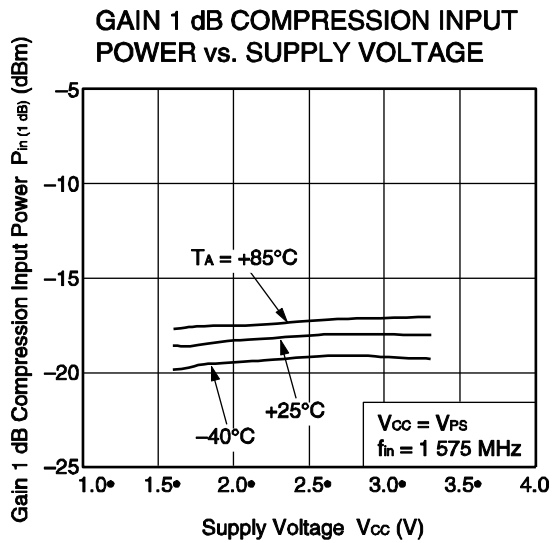
NOISE FIGURE vs. OPERATING AMBIENT TEMPERATURE



Remark The graphs indicate nominal characteristics.



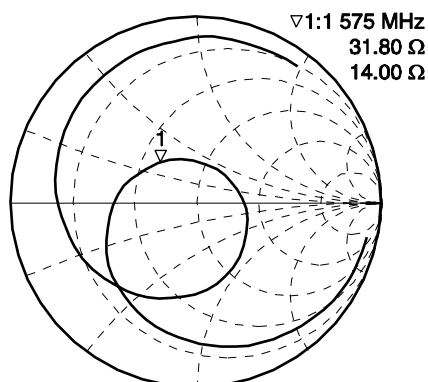
Remark The graphs indicate nominal characteristics.



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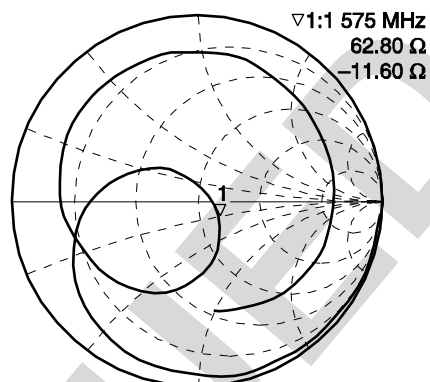
S-PARAMETERS ($T_A = +25^\circ\text{C}$, $V_{CC} = V_{PS} = 2.7\text{ V}$, monitored at connector on board)

S₁₁—FREQUENCY



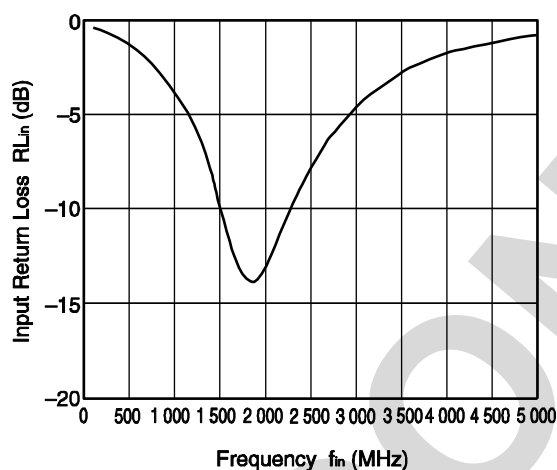
START 100.000 000 MHz STOP 5 000.000 000 MHz

S₂₂—FREQUENCY

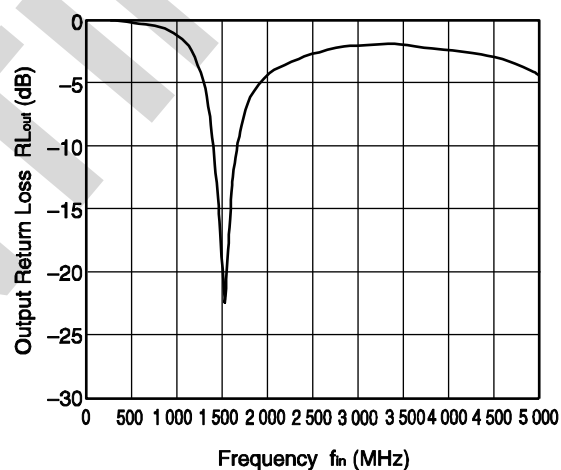


START 100.000 000 MHz STOP 5 000.000 000 MHz

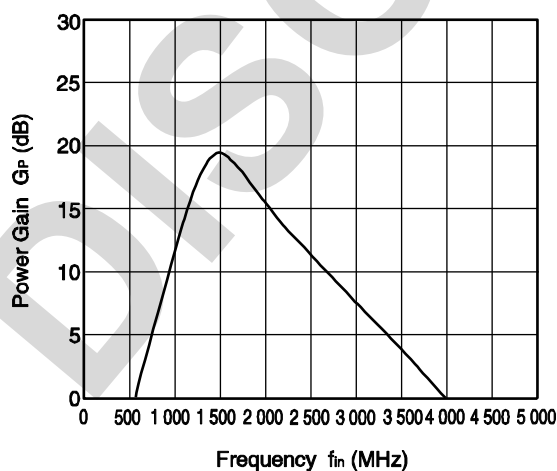
INPUT RETURN LOSS vs. FREQUENCY



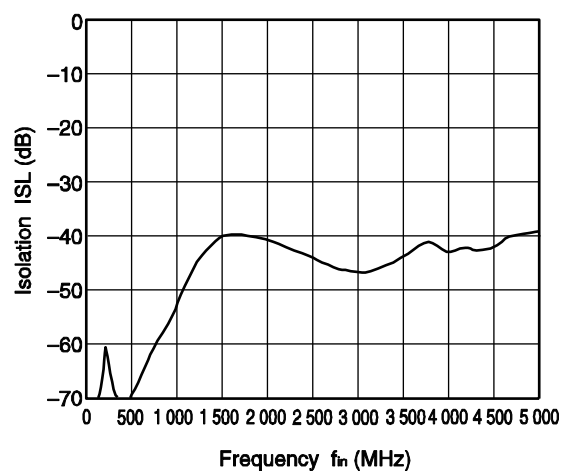
OUTPUT RETURN LOSS vs. FREQUENCY



POWER GAIN vs. FREQUENCY



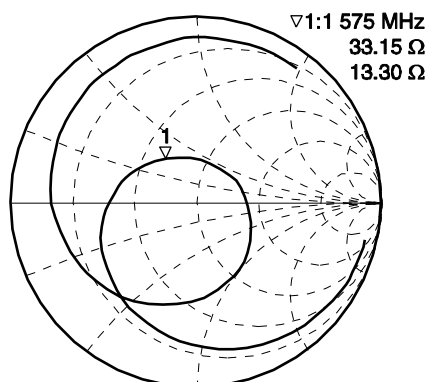
ISOLATION vs. FREQUENCY



Remark The graphs indicate nominal characteristics.

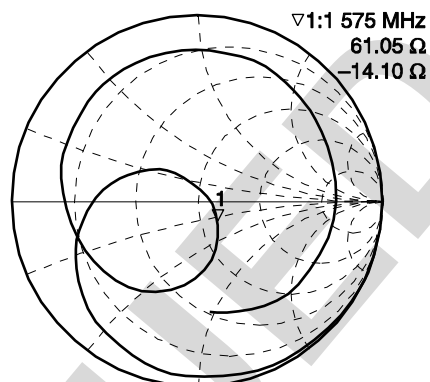
S-PARAMETERS ($T_A = +25^\circ\text{C}$, $V_{CC} = V_{PS} = 1.8\text{ V}$, monitored at connector on board)

S₁₁—FREQUENCY



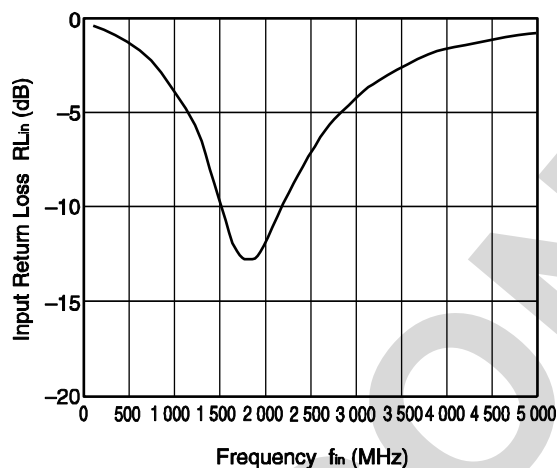
START 100.000 000 MHz STOP 5 000.000 000 MHz

S₂₂—FREQUENCY

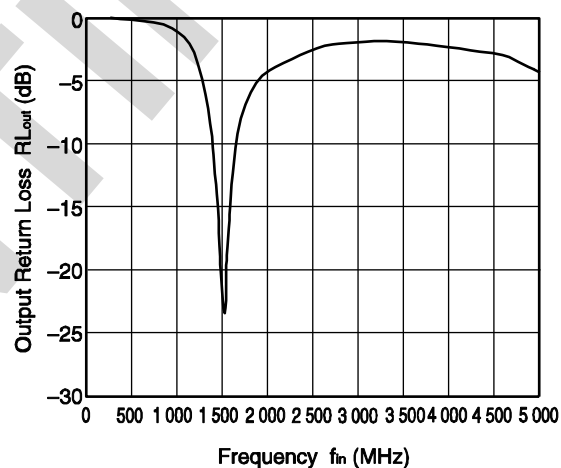


START 100.000 000 MHz STOP 5 000.000 000 MHz

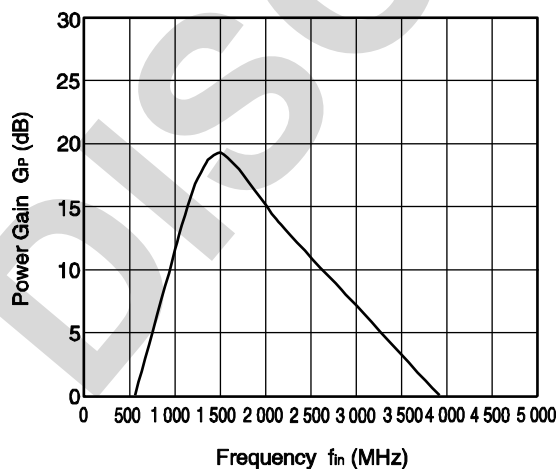
INPUT RETURN LOSS vs. FREQUENCY



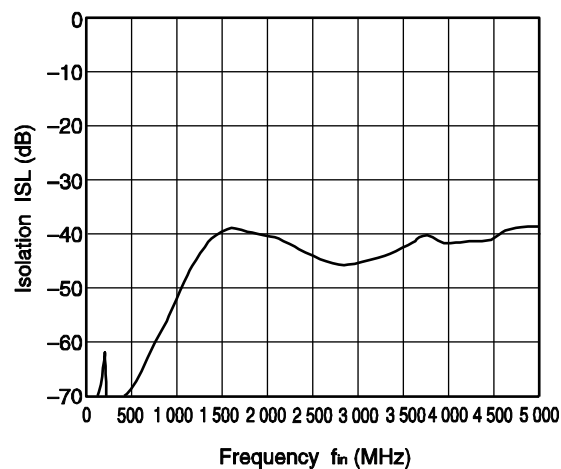
OUTPUT RETURN LOSS vs. FREQUENCY



POWER GAIN vs. FREQUENCY

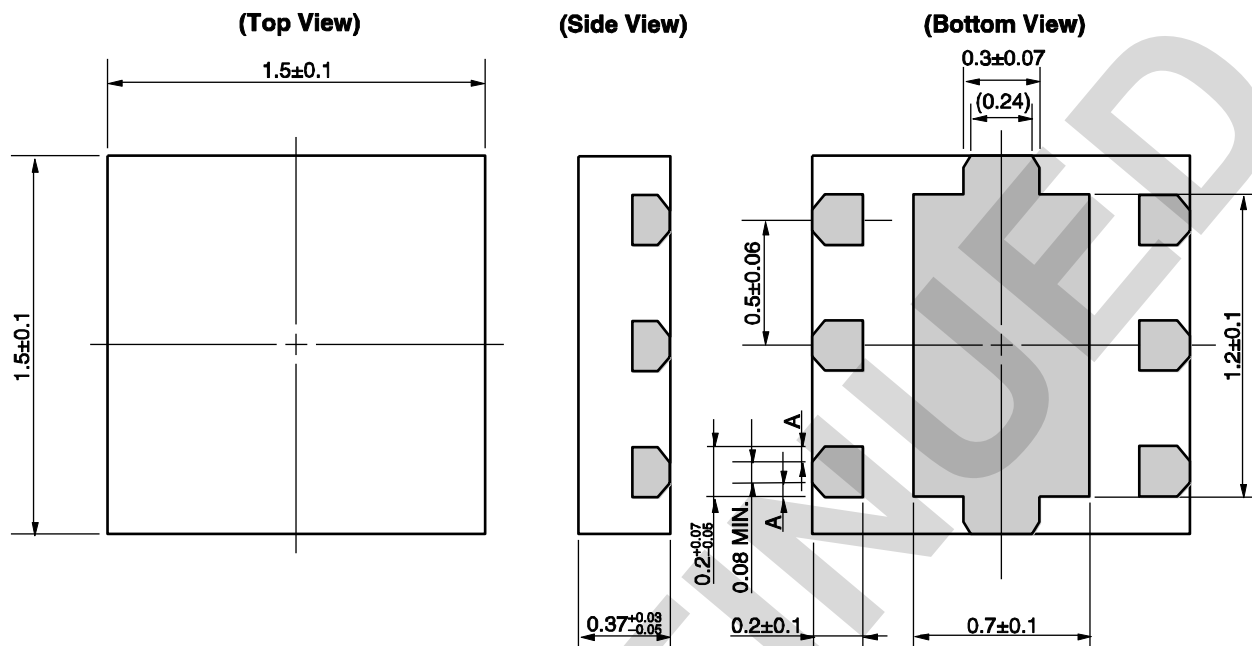


ISOLATION vs. FREQUENCY



Remark The graphs indicate nominal characteristics.

6-PIN PLASTIC TSON (T6N) (UNIT: mm)



() : Reference value

NOTES ON CORRECT USE

- (1) Observe precautions for handling because of electro-static sensitive devices.
- (2) Form a ground pattern as widely as possible to minimize ground impedance (to prevent undesired oscillation).
All the ground terminals must be connected together with wide ground pattern to decrease impedance difference.
- (3) The bypass capacitor should be attached to Vcc line.
- (4) Do not supply DC voltage to INPUT pin.

RECOMMENDED SOLDERING CONDITIONS

This product should be soldered and mounted under the following recommended conditions. For soldering methods and conditions other than those recommended below, contact your nearby sales office.

Soldering Method	Soldering Conditions	Condition Symbol
Infrared Reflow	Peak temperature (package surface temperature) : 260°C or below Time at peak temperature : 10 seconds or less Time at temperature of 220°C or higher : 60 seconds or less Preheating time at 120 to 180°C : 120±30 seconds Maximum number of reflow processes : 3 times Maximum chlorine content of rosin flux (% mass) : 0.2%(Wt.) or below	IR260
Wave Soldering	Peak temperature (molten solder temperature) : 260°C or below Time at peak temperature : 10 seconds or less Preheating temperature (package surface temperature) : 120°C or below Maximum number of flow processes : 1 time Maximum chlorine content of rosin flux (% mass) : 0.2%(Wt.) or below	WS260
Partial Heating	Peak temperature (terminal temperature) : 350°C or below Soldering time (per side of device) : 3 seconds or less Maximum chlorine content of rosin flux (% mass) : 0.2%(Wt.) or below	HS350

Caution Do not use different soldering methods together (except for partial heating).